

RoHS

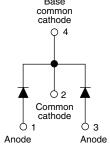
HALOGEN

FREE

Ultrafast Rectifier, 2 x 3 A FRED Pt®



TO-252AA (D-PAK)



	Base ommon athode	
	+	7
*	0 2	*
	ommon athode	
Ó 1		Ó 3
Anode		Anode

	O 4	
—	02	-

FEATURES

- · Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

PRODUCT SUMMARY				
Package	TO-252AA (D-PAK)			
I _{F(AV)}	2 x 3 A			
V_{R}	200 V			
V _F at I _F	0.9 V			
t _{rr} typ.	See Recovery table			
T _J max.	175 °C			
Diode variation	Common cathode			

DESCRIPTION / APPLICATIONS

Vishay Semiconductors' 200 V series are the state of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage	V_{RRM}		200	V	
Average rectified forward current per device	I _{F(AV)}	Total device, rated V _R , T _C = 159 °C	6		
Non-repetitive peak surge current	I _{FSM}		50	Α	
Peak repetitive forward current per diode	I _{FM}	Rated V _R , square wave, 20 kHz, T _C = 159 °C	6		
Operating junction and storage temperatures	T_J , T_{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-	
		I _F = 3 A	-	-	1	.,
Canada and and the same	ard voltage V _F	I _F = 3 A, T _J = 125 °C	-	-	0.9	V
Forward voltage		I _F = 6 A	-	-	1.2	
		I _F = 6 A, T _J = 125 °C	-	-	1.08	
Reverse leakage current I _R	$V_R = V_R$ rated	-	-	5		
	$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	100	μA	
Junction capacitance	C _T	V _R = 200 V	-	12	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nΗ





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	20	35	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	19	-	ns
		T _J = 125 °C		-	26	-	
Peak recovery current I _{RRM}		T _J = 25 °C	I _F = 3 A V _R = 160 V	-	3.1	-	Α
	T _J = 125 °C	$v_R = 160 \text{ V}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$	-	4.6	-	_ ^	
Poverse receivery charge	Q _{rr}	T _J = 25 °C		-	30	-	nC
Reverse recovery charge		T _J = 125 °C		-	60	-	110

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}	-65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}	-	-	5	
Thermal resistance, junction to ambient per leg	R _{thJA}	-	-	80	°C/W
Thermal resistance, case to heatsink	R _{thCS}	-	-	-	
Woight		-	0.3	-	g
Weight		-	0.01	-	OZ.
Mounting torque		6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-252AA (D-PAK) 6CWH02FNH		2FNH	

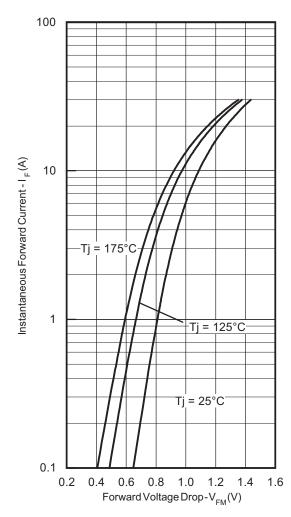


Fig. 1 - Maximum Forward Voltage Drop Characteristics

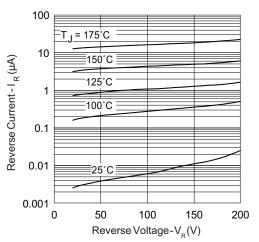


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

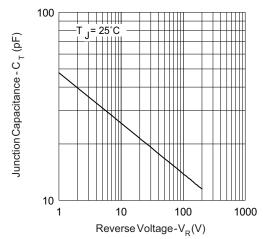


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

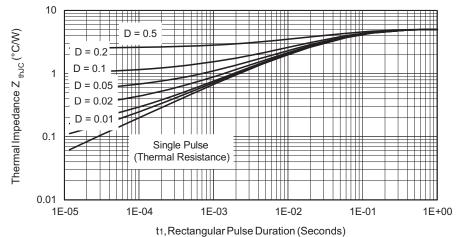


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

1000

1000

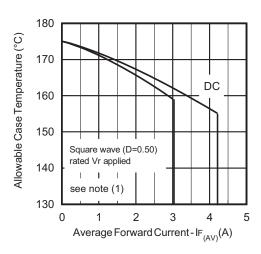


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

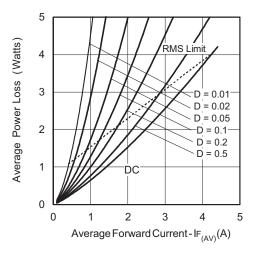
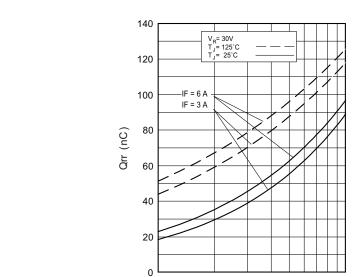


Fig. 6 - Forward Power Loss Characteristics



100

50

40

30

20

10

100

V_R= 30V T₁= 125°C

di F/dt (A/µs)

Fig. 7 - Typical Reverse Recovery vs. dI_F/dt

trr (nC)

 $di_F/dt~(A/\mu s)$ Fig. 8 - Typical Stored Charge vs. dI_F/dt

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

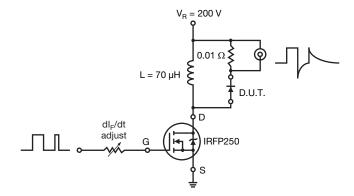
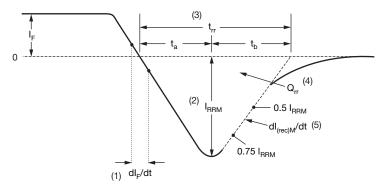


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

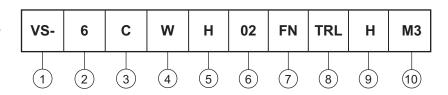
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating (6 = 6 A)
- Center tap configuration
- Package identifier:
 - W = D-PAK
- 5 H = hyperfast recovery
- 6 Voltage rating (02 = 200 V)
- 7 FN = TO-252AA
- None = tube (50 pieces)
 - TR = tape and reel
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 9 H = AEC-Q101 qualified
- 10 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-6CWH02FNHM3	75	3000	Antistatic plastic tube		
VS-6CWH02FNTRHM3	2000	2000	13" diameter reel		
VS-6CWH02FNTRRHM3	3000	3000	13" diameter reel		
VS-6CWH02FNTRLHM3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95519</u>				
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



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Vishay

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